University of Anbar
College of Science
Department of Physics



# فيزياء الحالة الصلبة Solid state Physics

المرحلة الرابعة الكورس الاول صلبة 1

# 6. Imperfections (defects) in solid materials العيوب في المادة الصلبة

#### 6.1 Point defects العيوب النقطية

Point defects are localized disruptions اخلال موضعي in otherwise perfect atomic or ionic arrangements الترتيب in a crystal structure. Even though we call them point defects, the disruption affects يؤثر a region الحين involving several عدد atoms or ions. These imperfections, shown المبينة in Figure 6.1, may be introduced انتقال of the atoms or ions when they gain خلال والمتعمد في المعاونة والمتعمد والمتعمد والمتعمد مناسبة والمتعمد المتعمد الم

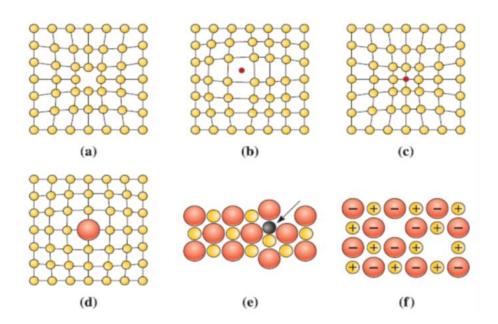


Figure 6.1 Point defects: (a) vacancy, (b) interstitial atom, (c) small substitutional atom, (d) large substitutional atom, (e) Frenkel defect, and (f) Schottky defect.

# 6.1.1 A vacancy: مكان شاغر

A vacancy is produced يتكون when an atom or an ion is missing ينفقد from its normal site مكانه الاعتيادي in the crystal structure as in Figure 6.1(a). When atoms or ions are missing تنفقد, the overall randomness العشوائية العامة or entropy of the material increases يزداد, which affects تؤثر the thermodynamic stability of a crystalline material. All crystalline materials have الاستقرار الثرموداينميكي into metals and alloys خلال during السبائك solidification عملية التصلب, at high temperatures, or as

a consequence ضرر الاشعاع Vacancies play ضرر الاشعاع. Vacancies play ضرر الاشعاع important role نتيجة in determining معدل the rate معدل at which atoms or ions move تتحرك or diffuse تتحرك in a solid material, especially in pure metals خصوصا

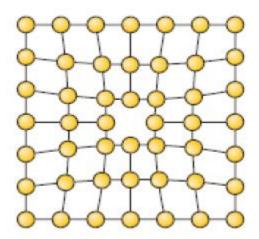


Fig. 6.1.a

At room temperature عند حرارة الغرفة (~298 K), the concentration تركيز of vacancies is small, but the concentration of vacancies increases يزداد exponentially كما as الحرارة as shown كما by the following بالتالي

$$n_v = n \exp\left(\frac{-Q_v}{RT}\right) \qquad \dots \dots \dots (1)$$

Where

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 $n_v$  is the number of vacancies per cm<sup>3</sup>;

n is the number of atoms per cm<sup>3</sup>;

 $Q_{\nu}$  is the energy required to produce one mole of vacancies, in cal/mol or Joules/mol;

R is the gas constant, 1.987  $\frac{Cal}{mol K}$  or 8.314  $\frac{Joules}{mol K}$  and;

T is the temperature in degrees Kelvin.

## **Example (6.1): The Effect of Temperature on Vacancy Concentrations.**

in FCC الفراغات of vacancies تركيز in FCC و of vacancies الفراغات in FCC ما at room temperature عرارة الغرفة at room temperature النحاس انداس is needed التي نحتاجها to heat treat copper الحرارة العرارة

the concentration of vacancies produced is 1000 times من المرات more than تو ازن the equilibrium اكثر من concentration of vacancies at room temperature? Assume that افترض ان 20,000 cal are required تحتاجها a mole of vacancies in copper.

#### **Solution:**

يوجد of FCC copper is 0.36151 nm. There are يوجد of FCC copper is 0.40151 nm. There are اربع نرات therefore الخلية, the number of copper atoms per cm<sup>3</sup> is:

$$n = \frac{4 \text{ atoms/cell}}{(3.6151 \times 10^{-8} \text{ cm})^3} = 8.466 \times 10^{22} \text{ copper atoms/cm}^3$$

At room temperature, T = 25 + 273 = 298 K:

$$n_v = n \exp\left(\frac{-Q_v}{RT}\right)$$

$$= \left(8.466 \times 10^{22} \frac{\text{atoms}}{\text{cm}^3}\right) \exp \left[\frac{-20,000 \frac{\text{cal}}{\text{mol}}}{\left(1.987 \frac{\text{cal}}{\text{mol} \cdot \text{K}}\right) (298 \text{ K})}\right]$$

$$= 1.814 \times 10^8 \text{ vacancies/cm}^3$$

To find a heat treatment temperature that will lead to a concentration of vacancies that is 1000 times higher than this number, or  $n_v$ = 1.814 x1011 vacancies/cm3.

We could do this by heating the copper to a temperature at which this number of vacancies forms:

$$n_{v} = 1.814 \times 10^{11} = n \exp\left(\frac{-Q_{v}}{RT}\right)$$
  
=  $(8.466 \times 10^{22}) \exp\left(-20,000\right)/(1.987T)$   
 $\exp\left(\frac{-20,000}{1.987T}\right) = \frac{1.814 \times 10^{11}}{8.466 \times 10^{22}} = 0.214 \times 10^{-11}$   
 $\frac{-20,000}{1.987T} = \ln(0.214 \times 10^{-11}) = -26.87$   
 $T = \frac{20,000}{(1.987)(26.87)} = 375 \text{ K} = 102^{\circ}\text{C}$ 

#### Example 6.2

Calculate the equilibrium number of vacancies per cubic meter for copper at 1000°C. The energy for vacancy formation is 0.9 eV/atom; the atomic weight and density (at 1000°C) for copper are 63.5 g/mol and 8.4 g/cm³, respectively.

#### Solution

This problem may be solved by using Equation 1; it is first necessary, however, to determine the value of N, the number of atomic sites per cubic meter for copper, from its atomic weight  $A_{Cu}$ , its density  $\rho$ , and Avogadro's number  $N_A$ , according to

$$N = \frac{N_{\text{A}}\rho}{A_{\text{Cu}}}$$

$$= \frac{(6.022 \times 10^{23} \, \text{atoms/mol})(8.4 \, \text{g/cm}^3)(10^6 \, \text{cm}^3/\text{m}^3)}{63.5 \, \text{g/mol}}$$

$$= 8.0 \times 10^{28} \, \text{atoms/m}^3$$

Thus, the number of vacancies at 1000°C (1273 K) is equal to

$$N_v = N \exp\left(-\frac{Q_v}{kT}\right)$$
  
=  $(8.0 \times 10^{28} \text{ atoms/m}^3) \exp\left[-\frac{(0.9 \text{ eV})}{(8.62 \times 10^{-5} \text{ eV/K})(1273 \text{ K})}\right]$   
=  $2.2 \times 10^{25} \text{ vacancies/m}^3$ 

# 6.1.2 Interstitial Defects العيوب الخلالية

An **interstitial defect** is formed عندما when عندما an extra atom ذرات اضاقیة or ion is inserted عنیادیا the crystal structure at a normally في داخل unoccupied عنیادیا position غیر مشغول , as in Figure 6.1 b

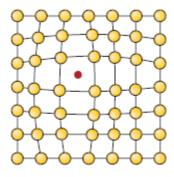


Fig. 6.1. b

Interstitial atoms or ions على الرغم من انها although, الذرات او الايونات الخلالية much smaller than الموجودة the atoms or ions located اصغر بكثير من at the lattice points الموجودة, are still larger than الا انها لاتزال اكبر من the interstitial sites في نقاط الشبيكة that they occupy التي تحتلها consequently المواقع البينية, the surrounding الحيط crystal region الحيز البلوري is compressed المحيط and distorted المحيط

# Example 6.3: Sites مواقع for Carbon in Iron

In FCC iron, carbon atoms are located تماني السطوح at the center في مركز of each edge في مركز of the unit cell at sites والتي of the unit cell at sites في مواقع such as أو عند الله عند (0, 0, 1/2) and at the center وفي مركز of the unit cell (1/2, 1/2, 1/2). In BCC iron, carbon atoms enter tetrahedral sites مواقع رباعية السطوح, such as (0, 1/2, 1/4). The lattice parameter is 0.3571 nm for FCC iron and 0.2866 nm for BCC iron. Assume that افترض ان carbon atoms have نصف قطر of 0.071 nm. Would we expect نتوقع a greater distortion نرة الكاربون الخلالية an interstitial carbon atom?

#### **Solution:**

We can calculate the size of the interstitial site in BCC iron at the (0, 1/2, 1/4) location with the help of Figure 6.2(a). The radius  $R_{BCC}$  of the iron atom is:

$$R_{\rm BCC} = \frac{\sqrt{3}a_0}{4} = \frac{(\sqrt{3})(0.2866)}{4} = 0.1241 \text{ nm}$$
  
From Figure 4-2(a), we find that  $(\frac{1}{2}a_0)^2 + (\frac{1}{4}a_0)^2 = (r_{\rm interstitial} + R_{\rm BCC})^2$   
 $(r_{\rm interstitial} + R_{\rm BCC})^2 = 0.3125a_0^2 = (0.3125)(0.2866 \text{ nm})^2 = 0.02567$   
 $r_{\rm interstitial} = \sqrt{0.02567} - 0.1241 = 0.0361 \text{ nm}$ 

For FCC iron, the interstitial site such as the (0, 0, 1/2) lies along  $\langle 001 \rangle$  directions. Thus, the radius of the iron atom and the radius of the interstitial site are [Figure 6.2(b)]:

$$R_{\text{FCC}} = \frac{\sqrt{2}a_0}{4} = \frac{(\sqrt{2})(0.3571)}{4} = 0.1263 \text{ nm}$$
  
 $2r_{\text{interstitial}} + 2R_{\text{FCC}} = a_0$ 

$$r_{\text{interstitial}} = \frac{0.3571 - (2)(0.1263)}{2} = 0.0523 \text{ nm}$$

The interstitial site in BCC iron is smaller than the interstitial site in FCC iron. Although both are smaller than the carbon atom, carbon distorts تشوه the BCC crystal structure more than اکثر من the FCC structure. As a result, fewer carbon atoms are expected to enter interstitial positions in BCC iron than in FCC iron.

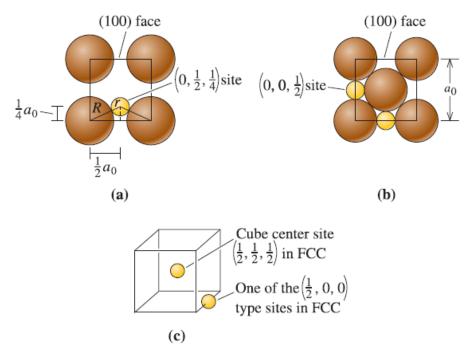
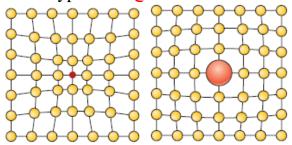


Figure 6.2 (a) The location of the (0, 1/2, 1/4) interstitial site in BCC metals. (b) (0, 0, 1/2) site in FCC metals. (c) Edge centers and cube centers are some of the interstitial sites in the FCC structure.

## 

A substitutional defect is created ينشاء او يتكون when one atom or ion is replaced بنوع مختلف by a different type بنوع مختلف of atom or ion as in Figure 6.1 c, d



Figs. 6.1. c and d

The substitutional atoms or ions الذرات او الايونات الابدالية occupy الذرات او الايونات الابدالية the normal lattice site موقع الشبيكة الاعتيادي. And they may either be larger وقد تكون اكبر than the normal atoms or ions الذرة او الايون الاعتيادي in the crystal structure, in which case المسافات البينية the surrounding المحيطة interatomic spacings المحيطة are

reduced مسببة causing مسببة the surrounding atoms الذرات المحيطة to have مسبنة larger interatomic spacings مسافات بينية اكبر

#### عيب فرانكل A Frenkel defect

يتشكل formed هو زوج فارغ – خلالي formed هو نقطة شبيكة اعتيادي a normal lattice point من a normal lattice point نقطة شبيكة اعتيادي behind تاركا behind تاركا behind الله موقع خلالي as in Figure 6.1e leaving المواغل behind عادة يرافق with ionic waterials . المواد الايونية a Frenkel defect can occur عيب فرانكل يمكن ان يوجد in metals المواد المرتبطة تساهميًا and covalently bonded materials في المعادن .

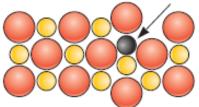


Fig. 6.1.e

## عيب شوتكى 6.1.5 A Schottky defect

A **Schottky defect** is unique مميز to ionic materials المواد الايونية and is commonly موجود found موجود in many ceramic materials في اغلب المواد السير اميكية in an ionically bonded material عندما توجد فراغات when vacancies occur في مواد in an ionically bonded material متر ابطة ايونيا as shown in figure 6.1. f.

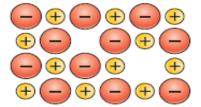


Fig. 6.1.f

# 6.2 Dislocations الانخلاعات

in an otherwise هي عيوب خطية in an otherwise perfect الانخلاعات crystal. They typically عادتا are created مثالية into في a crystal during عادتا of the material or when او عندما the material or when التصلب البلوري the material is deformed خلال permanently بالرغم من ان Although بشكل دائم permanently مشوهة Although بالرغم من ان are present بشكل دائم in all materials الانخلاعات ceramics بفي جميع المواد they are particularly البوليمر including السيراميك ceramics بضمنها and polymers بصورة عامة useful مفيدة useful مفيدة in explaining

strengthening التقوية in metallic materials في المواد المعدنية. We can identify يمكن ان three types في المواد المعدنية of dislocations

## 6.2.1 Screw Dislocations الإنخلاعات البرمية

Entrough خلال through خلال a perfect crystal البلورة المثالية a perfect crystal خزئيا and then skewing انحراف and then skewing البلورة المثالية a crystal by one atom spacing غرة واحدة a crystallographic plane و مستوي البلوري one revolution المحور the axis عول on which the crystal is skewed المستوي البلوري around عول البلوري around المحور around المحور equal atom spacings والمحور starting at point x and traveling المحور at point y one atom spacing ambient in each direction المحور at point y one atom spacing below our starting point. If a screw dislocation are not present معروب the loop would close المسار معلق the Burgers vector b غير موجود to complete المحور the rotation المحور is the Burgers vector b المحور a spiral path المحور around حول or line الخط around حول which it trace out حلزوني to the screw dislocation. The Burgers vector is parallel المسار the screw dislocation. The Burgers vector is parallel dislocation.

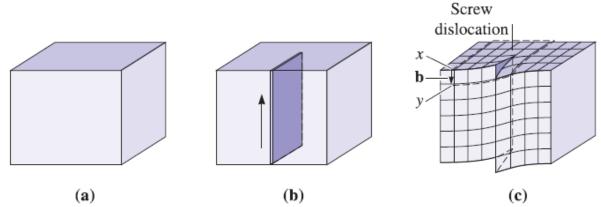


Figure 6.3 (a) The perfect crystal (b) is cut and sheared one atom spacing, and (c). The line along which shearing occurs is a screw dislocation. A Burgers vector **b** is required to close a loop of equal atom spacings around the screw dislocation.

# 6.2.2 Edge Dislocations الانخلاع الحافي

An edge dislocation (Figure 6.4) can be illustrated يتوضح by slicing بخرئي by through a perfect crystal, spreading ينتشر the crystal apart جزئي the crystal apart جزئي the crystal apart بنتشر of atoms. The bottom edge مستوي نصف اضافي of this inserted plane المستوي الداخل represents المستوي الداخل a clockwise الداخل a clockwise عقارب الساعة loop عقارب الساعة at point x and traveling انخلاع حافي around عناس around عناس وتنتقل at point x and traveling بدايتا at point x and traveling مسار an equal number بعدد متساوي at point y one atom spacing مسافة ذرية واحدة بكل اتجاه at point y one atom spacing مسافة ذرية واحدة واحدة partway

from the starting point من نقطة البداية. The Burgers vector is perpendicular to the dislocation. A "L" symbol is often used غالبا يستخدم to denote ليمثل an edge dislocation.

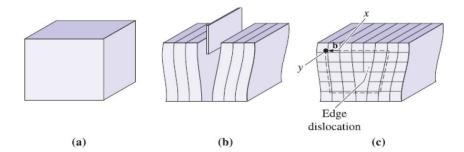


Figure 6-4 (a) The perfect crystal (b) in is cut and an extra half plane of atoms is inserted. (c) The bottom edge of the extra half plane is an edge dislocation. A Burgers vector b is required to close a loop of equal atom spacings around the edge dislocation.

## 6.2.3 Mixed Dislocations انخلاعات مختلطة

والبرمي and screw الحافي edge كلا من both كلا من and screw والبرمي and screw الحافي edge عدر انتقال and screw مكونات components مع حيز انتقال between them مع حيز انتقال between them مينهما. The Burgers vector لكل for all portions يبقى the same بيقى of the mixed dislocation.

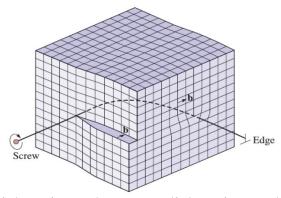


Figure 6.5 A mixed dislocation. The screw dislocation at the front face of the crystal gradually changes to an edge dislocation at the side of the crystal.

#### References

- 1- Charles Kittel Introduction to Solid State Physics-Wiley (2005)
- 2- J. S. Blakemore Solid State Physics-Cambridge University Press (1985)
- 3- M. A. OMAR Elementary-solid-state-physics